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June 2009

# FPF2300/02/03

## Dual-Output Current Limit Switch

### Features

- 1.8 to 5.5V Input Voltage Range
- Typical  $R_{ON} = 75m\Omega$  at  $I_N = 5.5V$
- 1.3A Current Limit (Typical)
- Slew Rate Controlled
- Reversed Current Blocking when Disabled
- ESD Protected, Above 4000V HBM
- Independent Thermal Shutdown
- UVLO
- RoHS Compliant

### Applications

- Notebook Computing
- Peripheral USB Ports
- Networking / USB Based Equipment

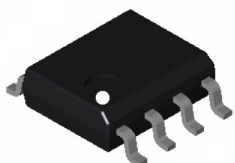


Figure 1. 8-Lead SOP

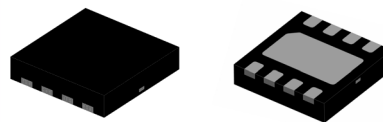


Figure 2. 8-Lead MLP (3x3mm)

### Description

The FPF2300/02/03 are dual-channel load switches of IntelliMAX™ family. The FPF2300/02/03 consist of dual, independent, current-limited, slew rate controlled, P-channel MOSFET power switches. Slew rated turn-on prevents inrush current from glitching supply rails. The input voltage range operates from 1.8V to 5.5V to fulfill today's USB device supply requirements. Switch control is accomplished by a logic input (ON) capable of interfacing directly with low-voltage control signal.

For the FPF2302, if the constant current condition persists after 10ms, these parts shut down the switch and pull the fault signal pin (FLAGB) LOW. The FPF2300 has an auto-restart feature that turns the switch on again after 504ms if the ON pin is still active. For the FPF2303, a current limit condition immediately pulls the fault signal pin LOW and the part remains in the constant-current mode until the switch current falls below the current limit. For the FPF2300 through FPF2303, the current limit is typically 1.3A for each switch to align with notebook computing applications. FPF2300/02/03 is available in both SO8 and MLP 3X3mm 8-lead packages.

### Ordering Information

| Part Number | Minimum Current Limit | Current Limit Blanking Time | Eco Status | Auto Restart | ON Pin Activity | Mode             | Package                               |
|-------------|-----------------------|-----------------------------|------------|--------------|-----------------|------------------|---------------------------------------|
| FPF2300MX   | 1100mA                | 10ms                        | RoHS       | 504ms        | Active LOW      | Restart          | 8-Lead SO8                            |
| FPF2302MX   | 1100mA                | 10ms                        | RoHS       | N/A          | Active LOW      | Latch Off        | 8-Lead SO8                            |
| FPF2303MX   | 1100mA                | 0ms                         | RoHS       | N/A          | Active LOW      | Constant Current | 8-Lead SO8                            |
| FPF2300MPX  | 1100mA                | 10ms                        | Green      | 504          | Active LOW      | Restart          | 8-Lead Molded Lead-less Package (MLP) |
| FPF2302MPX  | 1100mA                | 10ms                        | Green      | N/A          | Active LOW      | Latch Off        | 8-Lead Molded Lead-less Package (MLP) |
| FPF2303MPX  | 1100mA                | 0ms                         | Green      | N/A          | Active LOW      | Constant Current | 8-Lead Molded Lead-less Package (MLP) |



For Fairchild's definition of Eco Status, please visit: [http://www.fairchildsemi.com/company/green/rohs\\_green.html](http://www.fairchildsemi.com/company/green/rohs_green.html).

## Application Circuit

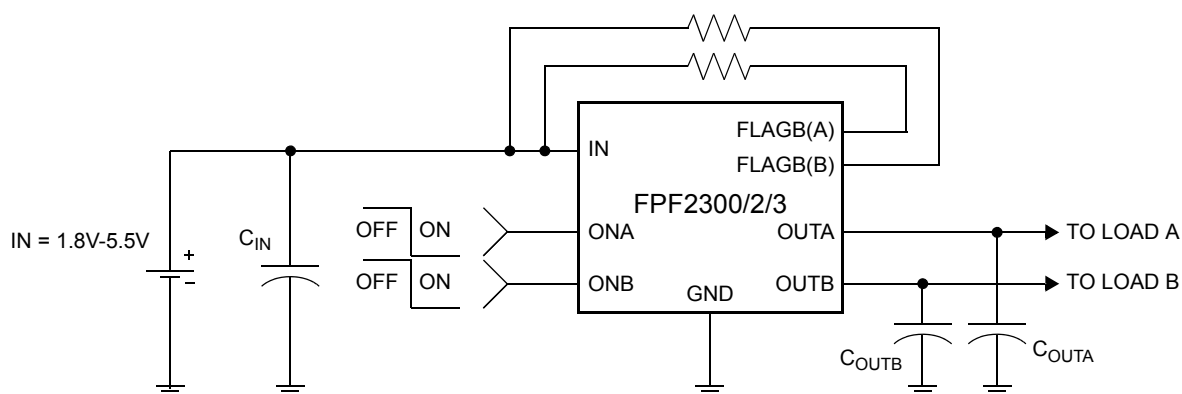


Figure 3. Typical Application

## Functional Block Diagram

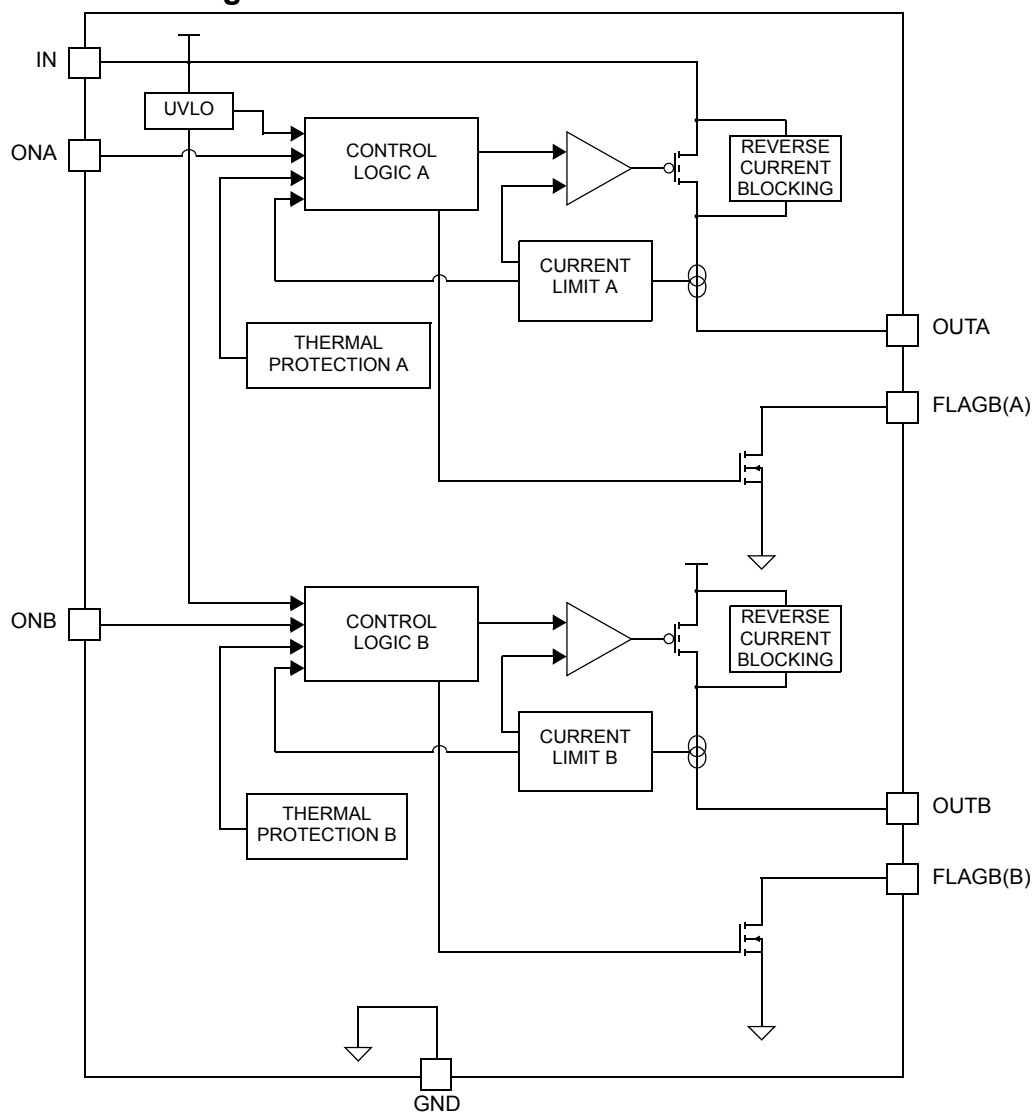


Figure 4. Block Diagram

## Pin Configuration

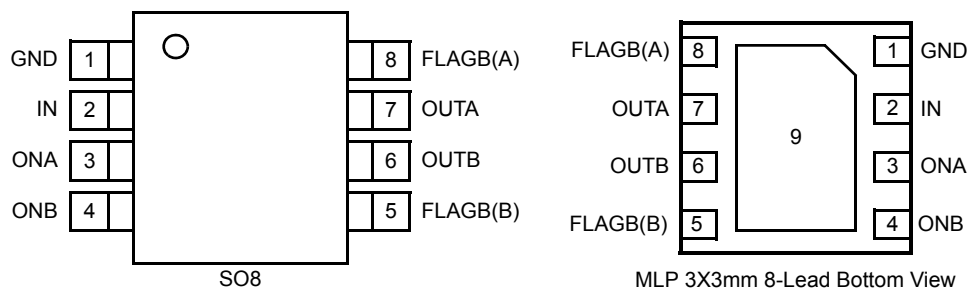


Figure 5. Pin Configurations

## Pin Description

| Pin #  | Name        | Function                                                                                                  |
|--------|-------------|-----------------------------------------------------------------------------------------------------------|
| 1      | GND         | Ground                                                                                                    |
| 2      | IN          | Supply Input: Input to the power switch and the supply voltage for the IC.                                |
| 3      | ONA         | ON / OFF control input of power switch A. Active LOW                                                      |
| 4      | ONB         | ON / OFF control input of power switch B. Active LOW                                                      |
| 5      | FLAGB(B)    | Fault Output B, Active LO, open drain output which indicates an over supply, UVLO and thermal shutdown.   |
| 6      | OUTB        | Switch Output: Output of the power switch B                                                               |
| 7      | OUTA        | Switch Output: Output of the power switch A                                                               |
| 8      | FLAGB(A)    | Fault Output A, Active LO, open drain output which indicates an over supply, UVLO and thermal shutdown.   |
| 9(MLP) | Thermal Pad | IC Substrate, which can be connected to GND for better thermal performance. Do not connect to other pins. |

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol           | Parameter                                           |                                   | Min. | Max.               | Unit |   |
|------------------|-----------------------------------------------------|-----------------------------------|------|--------------------|------|---|
|                  | IN, OUTA, OUTB, ONA, ONB, FLAGB(A), FLAGB(B) to GND |                                   | -0.3 | 6.0                | V    |   |
| P <sub>D</sub>   | Power Dissipation                                   | SO8                               |      | 0.8 <sup>(1)</sup> | W    |   |
|                  |                                                     |                                   |      | 1.4 <sup>(2)</sup> |      |   |
|                  |                                                     | MLP                               |      | 0.6 <sup>(3)</sup> |      |   |
|                  |                                                     |                                   |      | 2.2 <sup>(4)</sup> |      |   |
| T <sub>STG</sub> | Storage Temperature                                 |                                   | -65  | +150               | °C   |   |
| Θ <sub>JA</sub>  | Thermal Resistance, Junction-to-Ambient             | SO8                               |      | 158 <sup>(1)</sup> | °C/W |   |
|                  |                                                     |                                   |      | 92 <sup>(2)</sup>  |      |   |
|                  |                                                     | MLP                               |      | 216 <sup>(3)</sup> |      |   |
|                  |                                                     |                                   |      | 57 <sup>(4)</sup>  |      |   |
| ESD              | Electrostatic Discharge Protection                  | Human Body Model, JESD22-A114     |      | 4000               |      | V |
|                  |                                                     | Charged Device Model, JESD22-C101 |      | 2000               |      |   |

### Notes:

- Two-layer PCB of 2s0p from JEDEC STD 51-3.
- Four-layer PBD of 2s0p from JEDEC STD 51-7.
- Soldered thermal pad on a two-layer PCB without vias based on JEDEC STD 51-3.
- Soldered thermal pad on a four-layer with two vias connected with GND plane base on JEDEC STD 51-5, 7.

## Recommended Operating Range

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Symbol | Parameter                     | Min. | Max. | Unit |
|--------|-------------------------------|------|------|------|
| IN     | Supply Input                  | 1.8  | 5.5  | V    |
| $T_A$  | Ambient Operating Temperature | -40  | +85  | °C   |

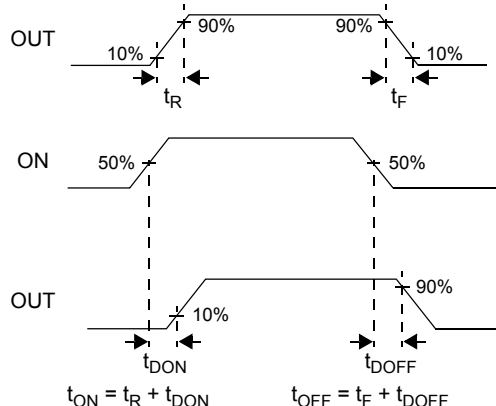
## Electrical Characteristics

IN = 1.8 to 5.5V, T<sub>A</sub> = -40 to +85°C unless otherwise noted. Typical values are at IN = 3.3V and T<sub>A</sub> = 25°C.

| Symbol                   | Parameter                         | Conditions                                                                           | Min. | Typ.  | Max. | Units |
|--------------------------|-----------------------------------|--------------------------------------------------------------------------------------|------|-------|------|-------|
| <b>Basic Operation</b>   |                                   |                                                                                      |      |       |      |       |
| V <sub>IN</sub>          | Operating Voltage                 |                                                                                      | 1.8  |       | 5.5  | V     |
| I <sub>Q</sub>           | Quiescent Current                 | IN = 5.5V, V <sub>ONA</sub> = V <sub>ONB</sub> = 0V, I <sub>OUT</sub> = 0mA          |      | 52.5  | 94.5 | μA    |
| I <sub>SD</sub>          | IN Shutdown Current               | V <sub>ONA</sub> = V <sub>ONB</sub> = 5.5V, IN = 5.5V<br>OUTA = OUTB = Short to GND, |      |       | 3    | μA    |
| R <sub>ON</sub>          | On Resistance                     | IN = 5.5V, I <sub>OUT</sub> = 200mA, T <sub>A</sub> = 25°C                           |      | 75    | 140  | mΩ    |
|                          |                                   | IN = 5.5V, I <sub>OUT</sub> = 200mA, T <sub>A</sub> = -40°C to 85°C                  |      | 90    |      |       |
| V <sub>IH</sub>          | ON Input Logic High Voltage (ON)  | IN = 1.8V                                                                            | 0.8  |       |      | V     |
|                          |                                   | IN = 5.5V                                                                            | 1.4  |       |      |       |
| V <sub>IL</sub>          | ON Input Logic Low Voltage        | IN = 1.8V                                                                            |      |       | 0.5  | V     |
|                          |                                   | IN = 5.5V                                                                            |      |       | 0.9  |       |
| I <sub>ON</sub>          | ON Input Leakage                  | V <sub>ON</sub> = IN or GND                                                          | -1   |       | 1    | μA    |
|                          | FLAGB Output Logic Low Voltage    | IN = 5.5V, I <sub>SINK</sub> = 1mA                                                   |      | 0.1   | 0.2  | V     |
|                          |                                   | IN = 1.8V, I <sub>SINK</sub> = 1mA                                                   |      | 0.15  | 0.30 |       |
|                          | FLAGB Output High Leakage Current | IN = V <sub>ON</sub> = 5V                                                            |      |       | 1    | μA    |
| <b>Protections</b>       |                                   |                                                                                      |      |       |      |       |
| I <sub>LIM</sub>         | Current Limit                     | IN = 3.3V, V <sub>OUTA</sub> = V <sub>OUTB</sub> = 3V, T <sub>A</sub> = 25°C         | 1.1  | 1.3   | 1.5  | A     |
| TSD                      | Thermal Shutdown                  | Shutdown Threshold                                                                   |      | 140   |      | °C    |
|                          |                                   | Return from Shutdown                                                                 |      | 130   |      |       |
|                          |                                   | Hysteresis                                                                           |      | 10    |      |       |
| V <sub>UVLO</sub>        | Under-Voltage Shutdown            | IN Increasing                                                                        | 1.55 | 1.65  | 1.75 | V     |
| V <sub>UVLO_HYS</sub>    | Under-Voltage Shutdown Hysteresis |                                                                                      |      | 50    |      | mV    |
| <b>Dynamic</b>           |                                   |                                                                                      |      |       |      |       |
| t <sub>ON</sub>          | Turn-On Time                      | R <sub>L</sub> = 500Ω, C <sub>L</sub> = 0.1μF                                        |      | 113.5 |      | μs    |
| t <sub>OFF</sub>         | Turn-Off Time                     | R <sub>L</sub> = 500Ω                                                                |      | 6     |      | μs    |
| t <sub>R</sub>           | OUTA, OUTB Rise Time              | R <sub>L</sub> = 500Ω, C <sub>L</sub> = 0.1μF                                        |      | 13.5  |      | μs    |
| t <sub>BLANK</sub>       | Over-Current Blanking Time        | PPF2300, PPF2302                                                                     | 5    | 10    | 20   | ms    |
| t <sub>RSTRT_BLANK</sub> | Startup FLAGB Blanking Time       | PPF2303 <sup>(5)</sup>                                                               | 5    | 10    | 20   | ms    |
| t <sub>RSRT</sub>        | Auto-Restart Time                 | PPF2300                                                                              |      | 504   |      | ms    |
| t <sub>CLR</sub>         | Current Limit Response Time       | IN = 3.3V, Moderate Over-Current Condition                                           |      | 20    |      | μs    |

### Note:

- PPF2303 has a 10ms startup FLAGB blanking time when the part is turned on via the ON pin to ensure transient load currents settle.



## Typical Characteristics

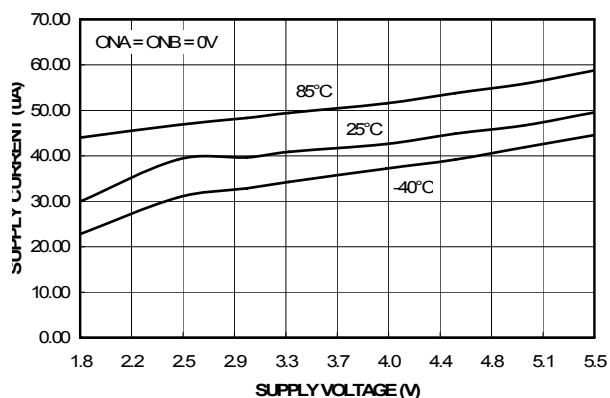


Figure 7. Quiescent Current vs. Supply Voltage

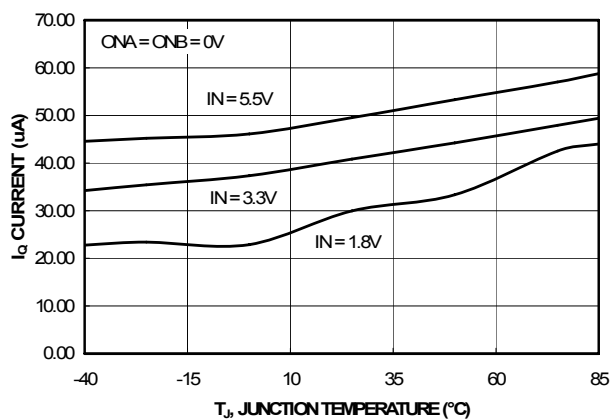


Figure 8. Quiescent Current vs. Temperature

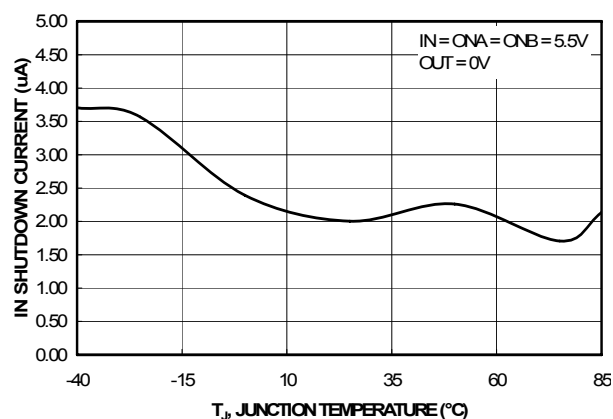


Figure 9. IN Shutdown Current vs. Temperature

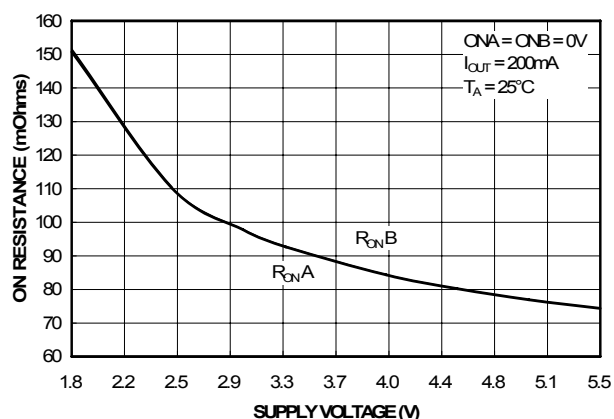


Figure 10.  $R_{ON}$  vs. Supply Voltage (MLP)

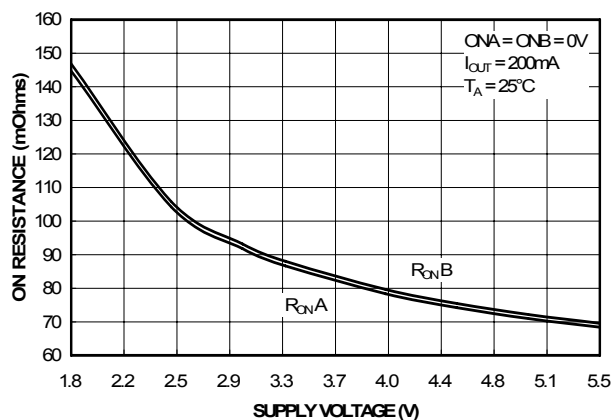


Figure 11.  $R_{ON}$  vs. Temperature (SO8)

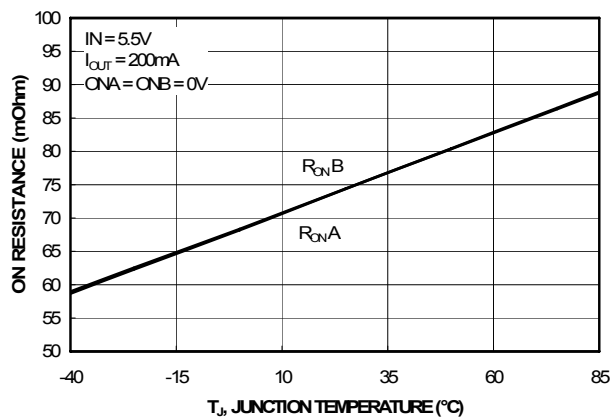


Figure 12.  $R_{ON}$  vs. Temperature (MLP)

## Typical Characteristics

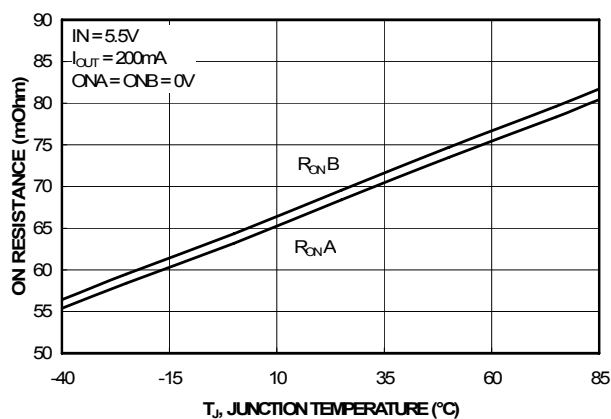


Figure 13.  $R_{ON}$  vs. Temperature (SO8)

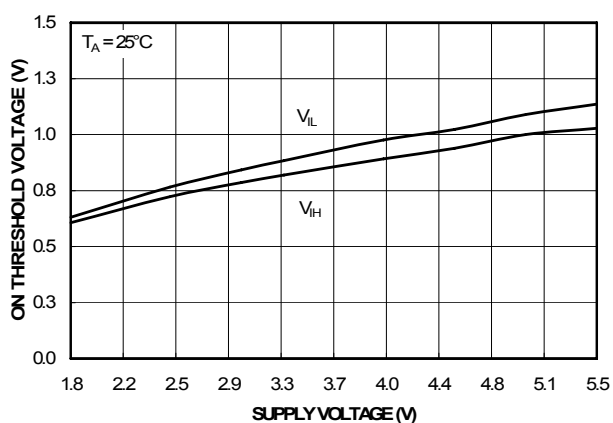


Figure 14. ON Threshold Voltage vs. Supply Voltage

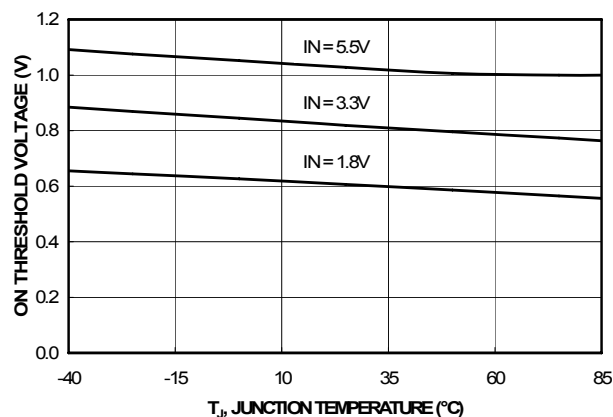


Figure 15. ON High Voltage vs. Temperature

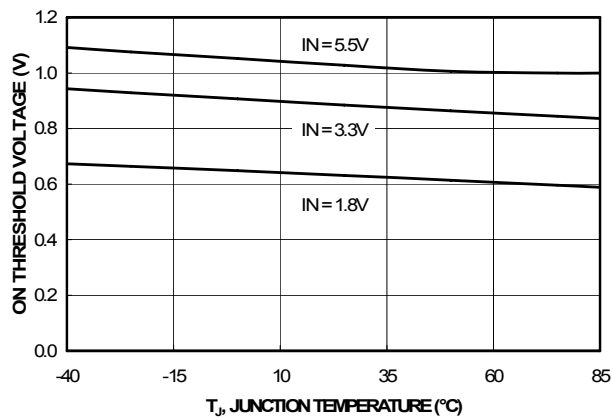


Figure 16. ON Low Voltage vs. Temperature

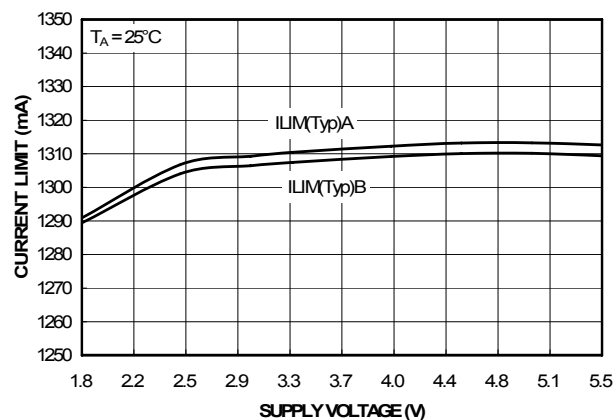


Figure 17. Current Limit vs. Supply Voltage

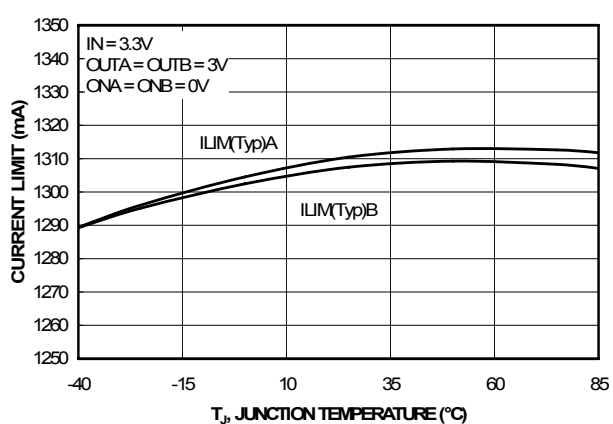


Figure 18. Current Limit vs. Temperature

## Typical Characteristics

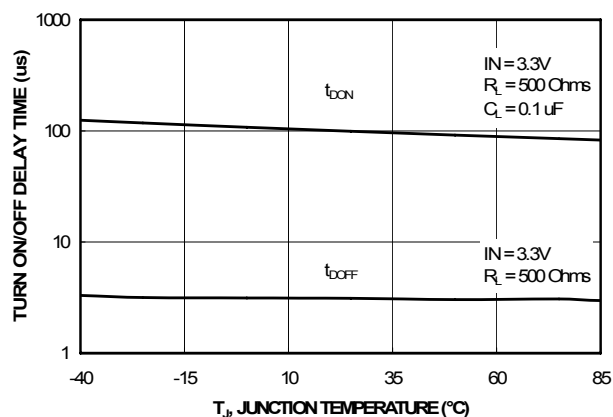


Figure 19.  $t_{DON}$  /  $t_{DOFF}$  vs. Temperature

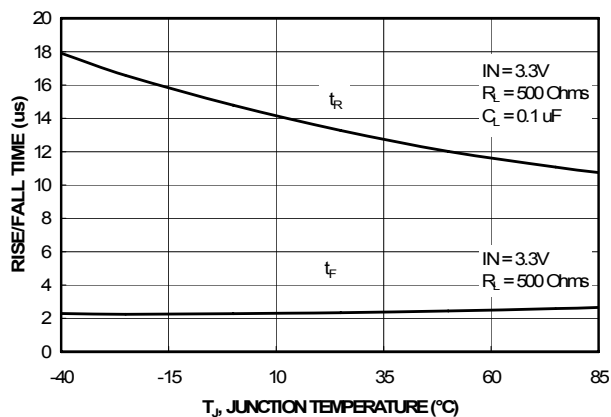


Figure 20.  $t_{RISE}$  /  $t_{FALL}$  vs. Temperature

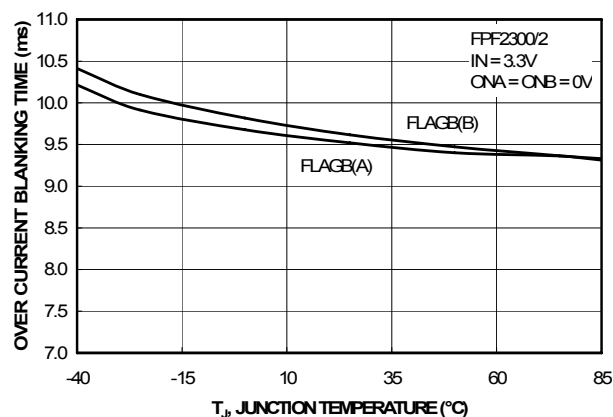


Figure 21.  $t_{BLANK}$  vs. Temperature

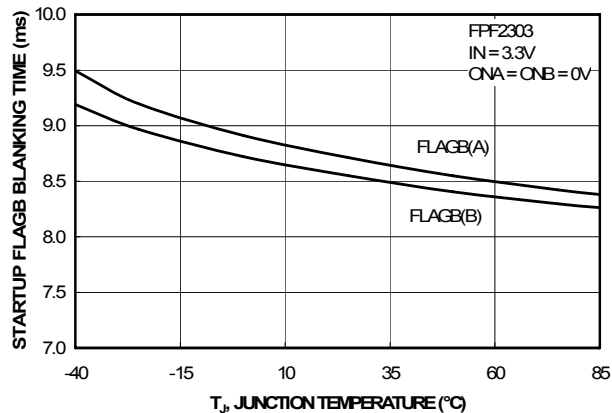


Figure 22.  $t_{RSTRT\_BLANK}$  vs. Temperature

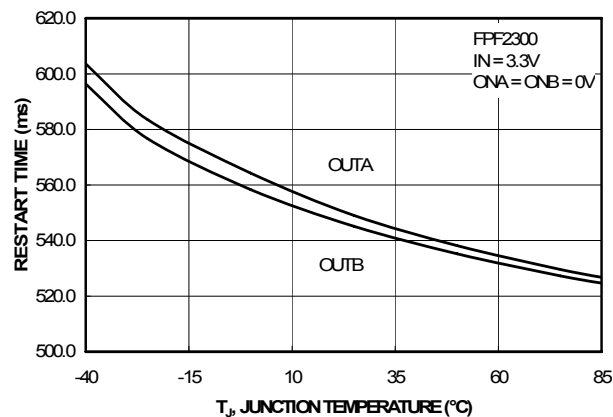


Figure 23.  $t_{RSTRT}$  vs. Temperature

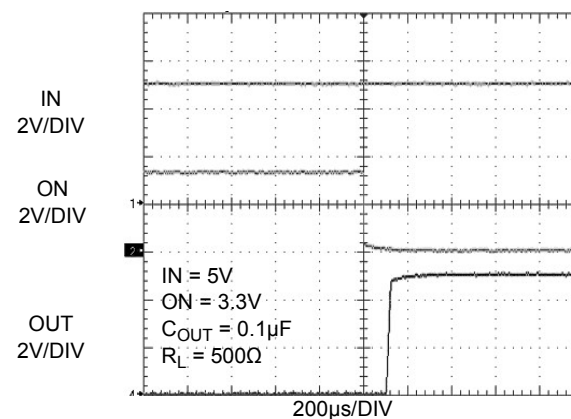


Figure 24.  $t_{ON}$  Response

## Typical Characteristics

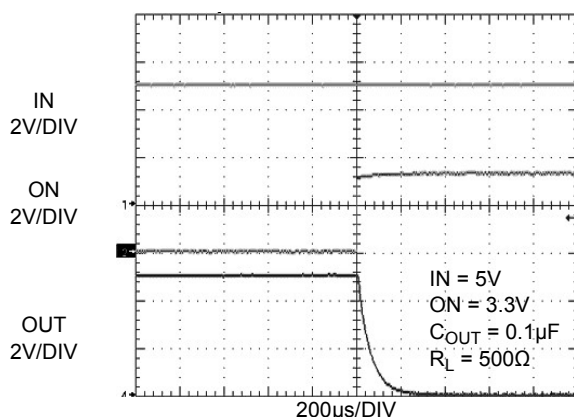


Figure 25.  $t_{OFF}$  Response

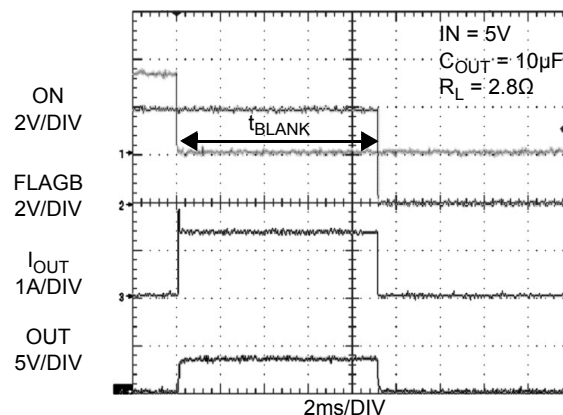


Figure 26. Over-Current Blanking Time (FPF2300/2)

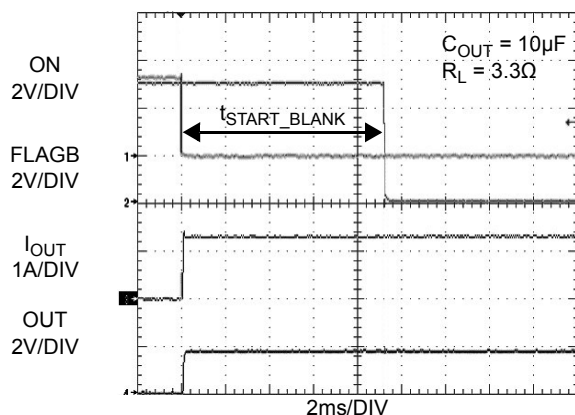


Figure 27. Startup FLAGB Blanking Time (FPF2303)

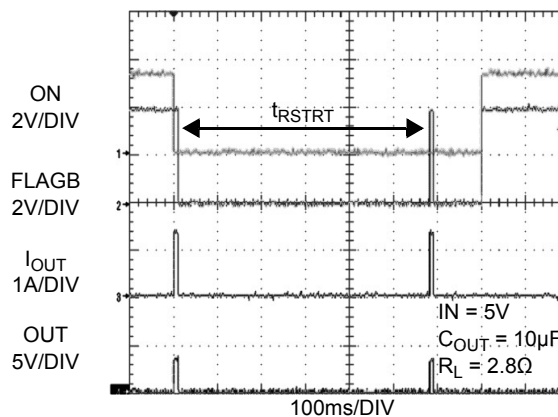


Figure 28. Auto-Restart Time (FPF2300)

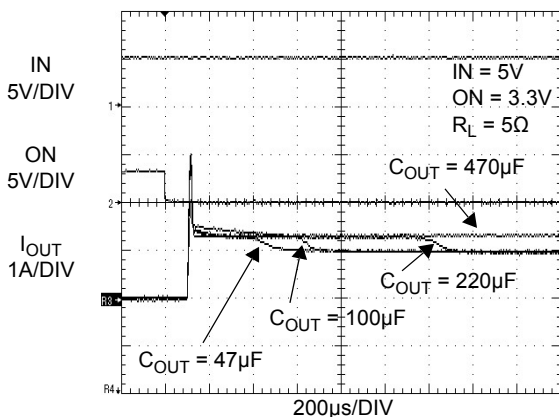


Figure 29. Current Limit at Startup with Different Output Capacitor

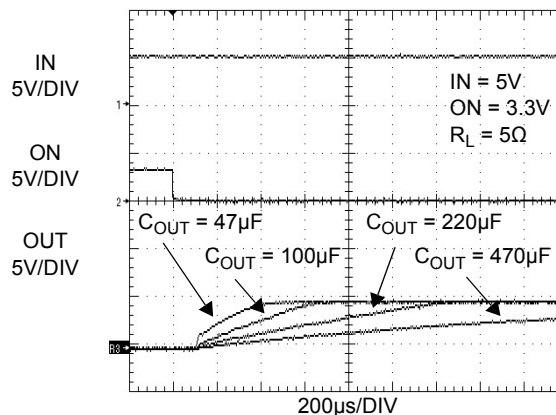


Figure 30. Output Voltage at Startup with Different Output Capacitor

## Typical Characteristics

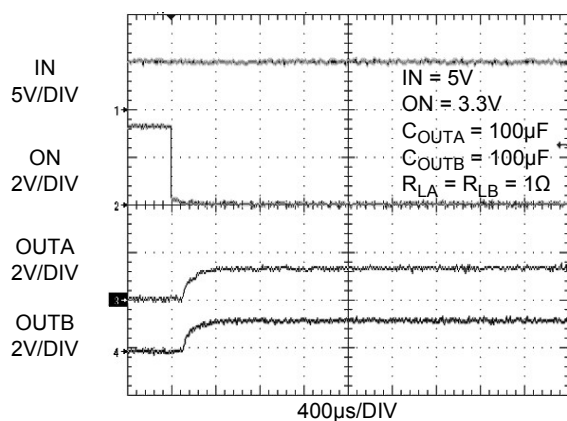


Figure 31. Current Limit Response Time Both Channels are in OC

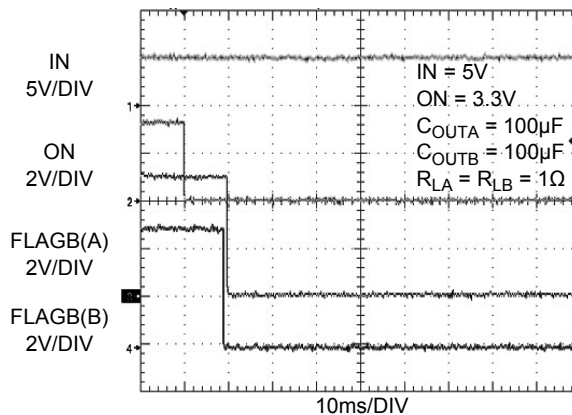


Figure 32. Startup FLAGB Blanking Time

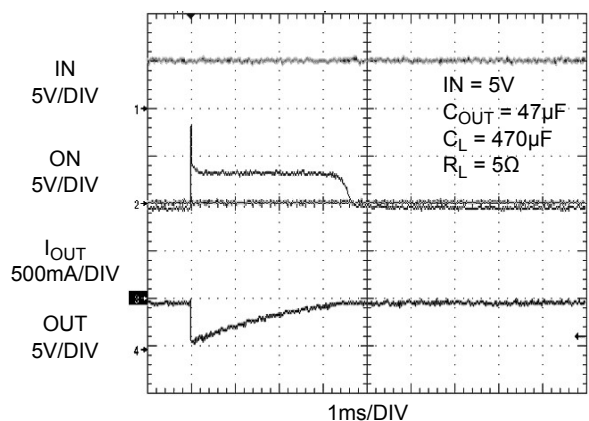


Figure 33. Inrush Response During Capacitive Load Hot Plug-In Event

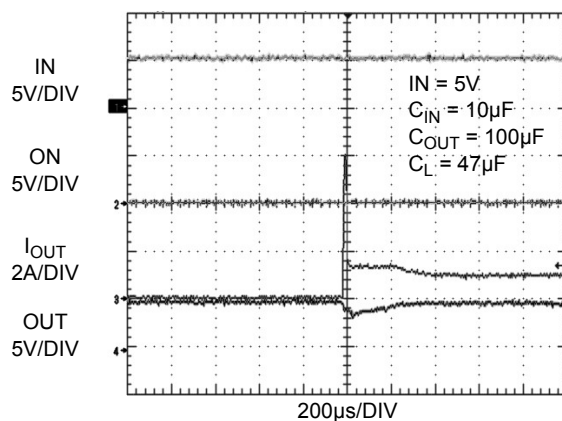


Figure 34. Inrush Response During Capacitive and Resistive Load Hot Plug-In Event

## Description of Operation

The PPF2300, PPF2302, and PPF2303 are dual-output current-limit switches designed to meet notebook computer, peripheral USB port, and point-of-load (POL) application power requirements. Dual-output current can be used where dual or quad USB ports are powered by hosts or self-powered hubs. The PPF230X family offers control and protection while providing optimum operation current for a safe design practice. The core of each switch is a typical 75mΩ ( $I_N = 5.5V$ ) P-channel MOSFET and a controller capable of functioning over an input operating range of 1.8-5.5V. The PPF230X family offers current limiting, UVLO (under-voltage lockout), and thermal shutdown protection per each switch. In the event of an over-current condition, the load switch limits the load to current limit value. The minimum current limit is set to 1100mA.

## On/Off Control

The ON pin is active LOW for PPF2300/2/3 and controls the state of the switch. Pulling the ON pin continuous to LOW holds the switch in the ON state. The switch moves into the OFF state when the ON pin is pulled HIGH or if a fault is encountered. For all versions, an under-voltage on input voltage or a junction temperature in excess of 140°C overrides the ON control to turn off the switch. In addition, excessive currents cause the switch to turn off in the PPF2300 and PPF2302 after a 10ms blanking time. The PPF2300 has an auto-restart feature that automatically turns the switch ON again after 504ms. For the PPF2302, the ON pin must be toggled to turn on the switch again. The PPF2303 does not turn off in response to an over-current condition, but remains operating in a constant-current mode as long as ON is enabled and the thermal shutdown or UVLO is not activated. The ON pin does not have a pull-down or pull-up resistor and should not be left floating.

## Current Limiting

The current limit ensures that the current through the switch doesn't exceed a maximum value, while not limiting at less than a minimum value. PPF230X family has dual-output load switches being housed in one package. The minimum current at which both switches start limiting the load current is set to 1100mA. The PPF2300 and PPF2302 have a blanking time of 10ms (typical), during which the switch acts as a constant current source. At the end of the blanking time, the switch is turned off. The PPF2303 has no current limit blanking period, so it remains in a constant current state until the ON pin of the affected switch is deactivated or the thermal shutdown turns off the switch.

## Fault Reporting

Over-current, input under-voltage, and over-temperature fault conditions are signaled out by the FLAGB pin going LOW. A UVLO fault is reported on both FLAGB(A) and FLAGB(B) simultaneously, while over-current and over-temperature condition faults are reported independently. PPF2300 and PPF2302 have a current fault blanking feature that prevents over-current faults shorter than the blanking time ( $t_{BLANK(Typ)} = 10ms$ ) from triggering the fault signal (FLAGB) output.

If the over-current condition persists beyond the blanking time, the PPF2300 pulls the FLAGB pin LOW and shuts the switch off. If the ON pin is kept active, an auto-restart feature releases the FLAGB pin and turns the switch on again after a 504ms auto-restart time ( $t_{RSTRT}$ ). If the over-current condition persists beyond the blanking time, the PPF2302 has a latch-off feature that pulls the FLAGB pin LOW and shuts the switch off. The switch is kept off and the FLAGB pin kept LOW until the ON pin is toggled. The PPF2303 responds to an overload condition by immediately pulling the FLAGB pin LOW and the switch remains in constant current mode until the output overload condition is removed. The PPF2303 has a

startup blanking feature that prevents current faults related to startup transients from triggering the FLAGB output. The startup blanking feature is effective for the first 10ms (typical) following device turn-on via ON pin.

The FLAGB outputs are two open-drain MOSFETs that require a pull-up resistor on each FLAGB pin. FLAGB can be pulled HIGH to a voltage source other than input supply with maximum 5.5V. A 100KΩ pull-up resistor is recommended. When the ON pin is inactive, the FLAGB is disabled to reduce current draw from the supply. If the FLAGB is not used, the FLAGB can be connected to ground on the PCB.

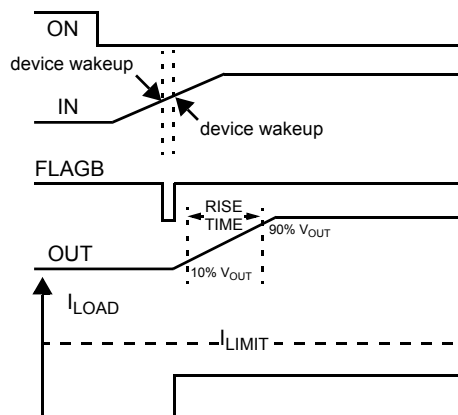


Figure 35. FLAGB Assertion in Under-Voltage Fault

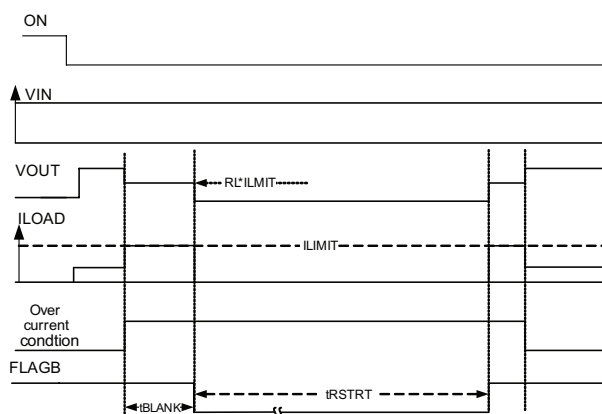
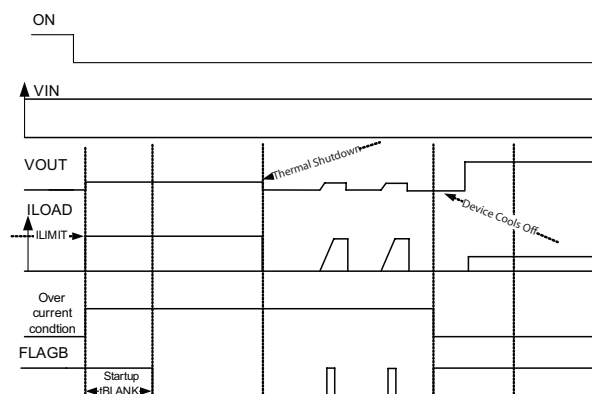


Figure 36. PPF2300 FLAGB Reports While Entering into an Over-Current Condition

### Note:

6. An over-current condition signal loads the output with a heavy load current larger than  $I_{LIM}$  value.



**Figure 37. FPF2300 FLAGB While and Over-Current Condition is Applied**

**Note:**

- An over-current condition signal loads the output with a heavy load current larger than  $I_{LIMIT}$  value.

### Under-Voltage Lockout (UVLO)

The under-voltage lockout feature turns off the switch if the input voltage drops below the under-voltage lockout threshold. With the ON pin active (ON pin pulled LOW), the input voltage rising above the under-voltage lockout threshold causes a controlled turn-on of the switch and limits current overshoot. If a device is in UVLO condition, both FLAGBs go LOW and indicate the fault condition. The device detects the UVLO condition when input voltage goes below UVLO voltage, but remains above 1.3V (typical).

### Reverse Current Blocking

Each switch of FPF2300/2/3 has an independent reverse current blocking feature that protects input source against current flow from output to input. For a standard USB power design, this is an important feature that protects the USB host from being damaged due to reverse current flow on  $V_{BUS}$ . To activate the reverse current blocking, the switch must be in OFF state (ON pins inactivated) so that no current flows from the output to the input. The FLAGB operation is independent of the reverse current blocking and does not report a fault condition if this feature is activated.

### Thermal Shutdown

The thermal shutdown protects the device from internally or externally generated excessive temperatures. Each switch has an individual thermal shutdown protection function and operates independently as adjacent switch temperatures increase above 140°C. If one switch is in normal operation and shutdown protection of second switch is activated, the first channel continues to operate if the affected channel's heat stays confined. The over-temperature in one channel can shut down both switches due to rapidly generated excessive load currents resulting in very high power dissipation. Generally, a thermally improved board layout can provide heat sinking and allow heat to stay confined and not affect the second switch operation.

During an over-temperature condition, the FLAGB is pulled LOW and the affected switch is turned off. If the temperature of the die drops below the threshold temperature, the switch

automatically turns on again. To avoid unwanted thermal oscillations, a 10°C (typical) thermal hysteresis is implemented between thermal shutdown entry and exit temperatures.

If output of both switches are connected together and an excessive load current activates thermal protection of both, the controller can shut down the switches after both FLAGB outputs go LOW and turn on both channels again. This provides simultaneous switch turn on. Thermal protection is for device protection and should not be used as regular operation.

### Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush currents when the switch is turned on into discharged load capacitors or a short-circuit; an input capacitor,  $C_{IN}$ , is recommended between IN and GND. The FPF2310/2/3/3L features a fast current limit response time of 20μs. An inrush current (also known as surge current) could occur during the current limit response time while the switch is responding to an over-current condition caused by large output capacitors. A 10μF ceramic capacitor,  $C_{IN}$ , is required to provide charges for the inrush current and prevent input voltage drop at turn on. Higher values of  $C_{IN}$  can be used to further reduce voltage drop.

### Output Capacitor

A 0.1μF to 1μF capacitor,  $C_{OUT}$ , should be placed between the OUT and GND pins. This capacitor prevents parasitic board inductances from forcing output voltage below GND when the switch turns off. This capacitor should have a low dissipation factor. An X7R MLCC (Multilayer Ceramic Chip) capacitors is recommended.

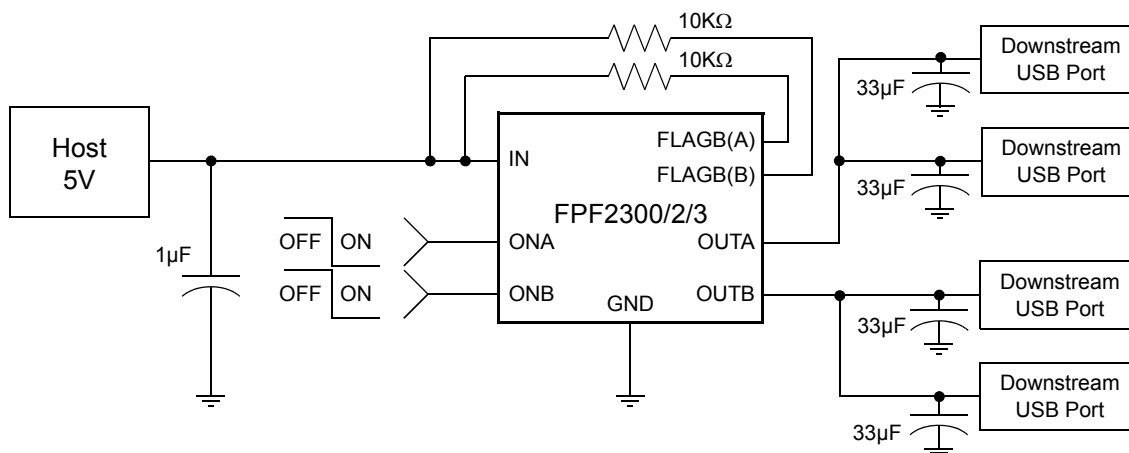
For the FPF2300 and FPF2302, the total output capacitance needs to be kept below a maximum value,  $C_{OUT(MAX)}$ , to prevent the part from registering an over-current condition beyond the blanking time and shutdown. The maximum output capacitance for a given input voltage can be determined from the following:

$$C_{OUT(MAX)} = \frac{I_{LIM(MIN)} \times t_{BLANK(MIN)}}{V_{IN}} \quad (1)$$

For example, in a 5V application,  $C_{OUT(MAX)}$  can be determined as:

$$\begin{aligned} C_{OUT(MAX)(IN = 5V)} &= \frac{1.1A \times 5ms}{5} \quad (2) \\ &= 1.1mF \end{aligned}$$

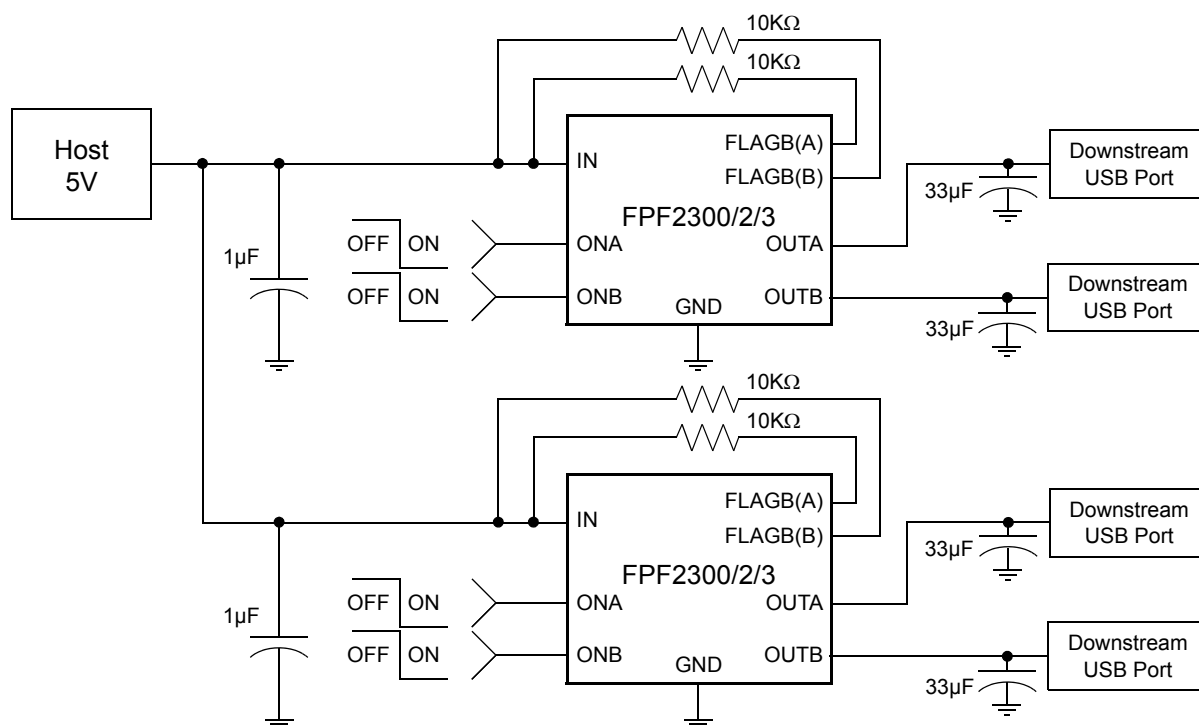
## Application Information



**Figure 38. Self Powered 4-Port USB Hub Using a Single FPF230X**

FPF230X is designed to simplify USB port power design based on self-powering USB host/hub applications. A self-powering USB port is powered by a local 5V power supply, not by an upstream port. Each port should supply at least 500mA to each downstream function based on USB 2.0 specification. Implementation can depend on the number of USB ports and current

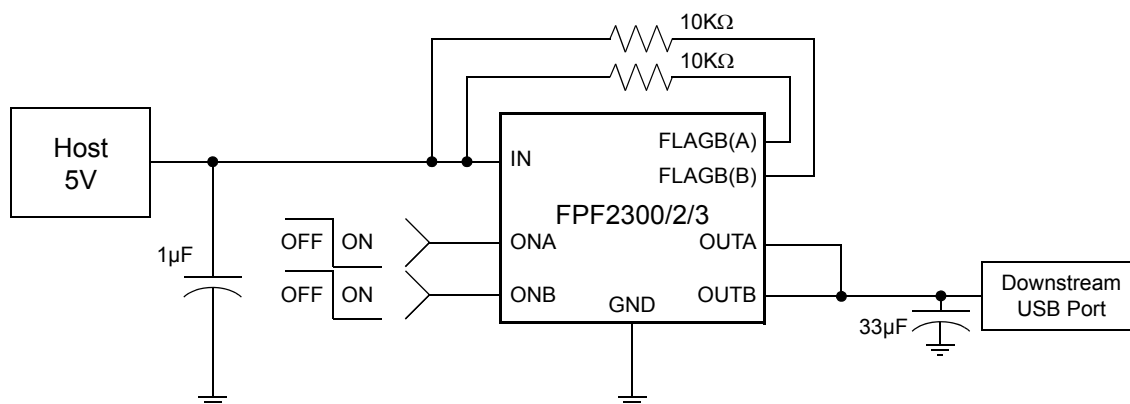
capability per port required in actual power designs. FPF230X has 1.1A minimum current limit per output, which can cover two ports, as shown in Figure 38. Four USB ports can be implemented with a single FPF230X part and current limiting is provided based on a two-port basis for a cost-effective solution.



**Figure 39. Individual Port Power Management for Self-Powered 4-Port USB Hub**

In Figure 39, each USB port is connected with each output. Four USB ports can be implemented with two FPF230X parts. Current limiting and control are provided based on a single port.

Current capability per port has more headroom; up to a minimum of 1.1A per port.



**Figure 40. Self-Powered USB Port for High Current Demand**

High current, over 2A, is sometimes required to supply enough power to downstream functions. As shown in Figure 40, a 2.2A

minimum load current can be achieved by tying dual outputs together.

## Power Dissipation

During normal operation as a switch, the power dissipation of the device is small and has little effect on the operating temperature of the part. The maximum power dissipation for both switches while the switch is in normal operation occurs just before both channels enter into current limit. This may be calculated using the formula:

$$P_{D\_MAX(Normal\ Operation)} = 2 \times (I_{LIM(MIN)})^2 \times R_{ON(MAX)} \quad (3)$$

For example, for a 5V application, maximum normal operation power loss while both switches delivering output current up to 1.1A, can be calculated as:

$$P_{D\_MAX(Normal\ Operation)(IN = 5V)} = 2 \times (1.1)^2 \times 0.14 \quad (4)$$

$$= 338mW$$

The maximum junction temperature should be limited to 125°C under normal operation. Junction temperature can be calculated using the formula below:

$$T_J = P_D \times R_{\theta JA} + T_A \quad (5)$$

where:

$T_J$  is junction temperature;

$P_D$  is power dissipation across the switch;

$R_{\theta JA}$  is thermal resistance junction to ambient of the package;

$T_A$  is ambient temperature.

For the example,  $T_{J(MAX)(Normal\ operation)}$  for an SO8 package with  $T_A=25^\circ C$  while both switches are delivering up to 1.1A is calculated as:

$$T_{J(MAX)(Normal\ Operation)} = P_{D\_MAX(Normal\ Operation)(IN = 5V)} \times 125 + 25 \quad (6)$$

$$= 78.4^\circ C$$

If the part goes into current limit, the maximum power dissipation occurs when the output of switch is shorted to ground. For the FPF2300 the power dissipation scales with the auto-restart time,  $t_{RSTRT}$ , and the over-current blanking time,  $t_{BLANK}$ . In this case, the maximum power dissipated for the FPF2300 is::

$$P_{D\_MAX(CurrentLimit)} = 2 \times \frac{t_{BLANK}}{t_{BLANK} + t_{RSTRT}} \times I_{N(MAX)} \times I_{LIM(MAX)} \quad (7)$$

which results in:

$$P_{D\_MAX(CurrentLimit)} = 2 \times \frac{10}{10 + 504} \times 5.5 \times 1.5 = 321mW \quad (8)$$

Note that this is below the maximum package power dissipation and the thermal shutdown feature protection provides additional safety to protect the part from damage due to excessive heating. The junction temperature is only able to increase to the thermal shutdown threshold. Once this temperature has been reached, toggling ON has no affect until the junction temperature drops below the thermal shutdown exit temperature. For the FPF2303, a short on both outputs causes both switches to operate in a constant current state and dissipate a worst-case power of:

$$P_{MAX} = 2 \times I_{N(MAX)} \times I_{LIM(MAX)} = 2 \times 5.5 \times 1.5 = 16.5\ W \quad (9)$$

As both FPF2303 outputs are connected to GND.

This power dissipation is significant and activates both thermal shutdown blocks and the part can cycle in and out of thermal shutdown as long as the ON pin is activated (pulled LOW) and the output short is present.

## PCB Layout Recommendations

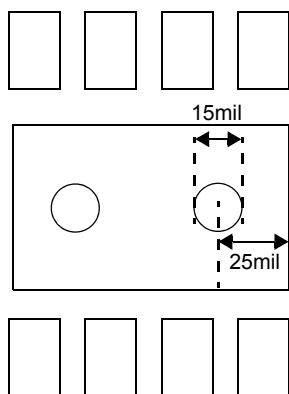
For the best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal and short-circuit operation. Using wide traces for IN, OUTs, and GND pins helps minimize parasitic electrical effects and the case-to-ambient thermal impedance.

### Improving Thermal Performance

Improper layout could result in higher junction temperature and triggering the thermal shutdown protection feature. This concern is particularly significant for the PPF2303, where both channels operate in constant current mode in the overload conditions and during fault condition the outputs are shorted, resulting in large voltage drop across switches. In this case, power dissipation of the switch ( $P_D = (V_{IN} - V_{OUT}) \times I_{LIM(MAX)}$ ) could exceed the maximum absolute power dissipation of part.

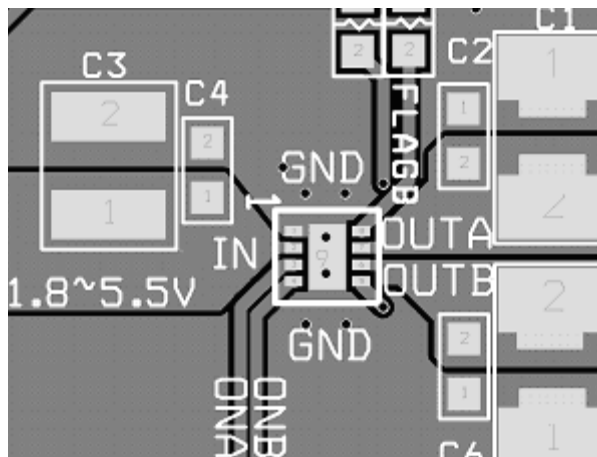
The following techniques improve the thermal performance of this family of devices. These techniques are listed in order of the significance of impact.

1. Thermal performance of the load switch can be improved by connecting the DAP (Die Attach Pad) of MLP 3x3mm package to the GND plane of the PCB.
2. Embedding two exposed through-hole vias into the DAP (pin 9) provides a path for heat to transfer to the back GND plane of the PCB. A drill size of round, 15 mils (0.4mm), with 1-ounce copper plating is recommended to create appropriate solder reflow. A smaller size hole prevents the solder from penetrating into the via, resulting in device lift-up. Similarly, a larger via hole consumes excessive solder and may result in voiding of the DAP.



**Figure 41. Two Through-Hole Open Vias Embedded in DAP**

3. The IN, OUTs, and GND pins dissipate most of the heat generated during a high load current condition. Figure 42 illustrates a proper layout for devices in MLP 3x3mm packages. IN, OUTs, and GND pins are connected to adequate copper so heat may be transferred as efficiently as possible out of the device. The low-power FLAGB and ON pin traces may be laid out diagonally from the device to maximize the area available to the ground pad. Placing the input and output capacitors as close to the device as possible also contributes to heat dissipation, particularly during high load currents.



**Figure 42. Proper Layout of Output and Ground Copper Area**

## FPF230X Evaluation Board

The FPF230X evaluation board has components and circuitry to demonstrate FPF2300/2/3 load switch functions and features, accommodating both the MLP 3x3mm and SO8 packages. The state of the each channel can be configured using J1 and J2 jumpers. In addition, both channels can be controlled by ONA and ONB test pints. Thermal performance of the board is improved using techniques in the layout recommendations section. R3 and R4 resistors are used on the board to sink a light load current when switches are activated.

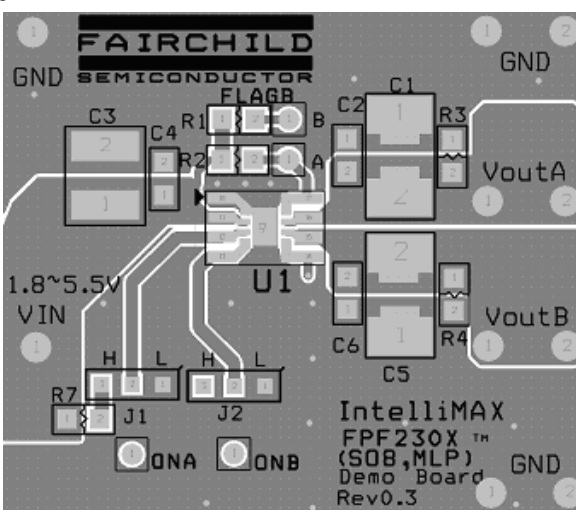


Figure 43. Top, SST and AST Layers  
(MLP 3x3mm and SO8)

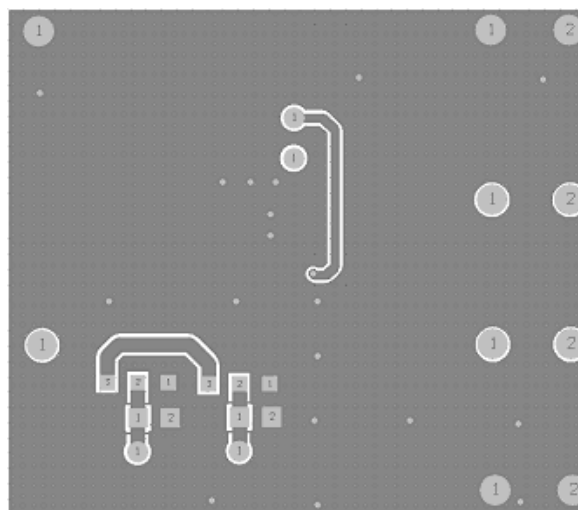


Figure 44. Bottom and ASB Layers

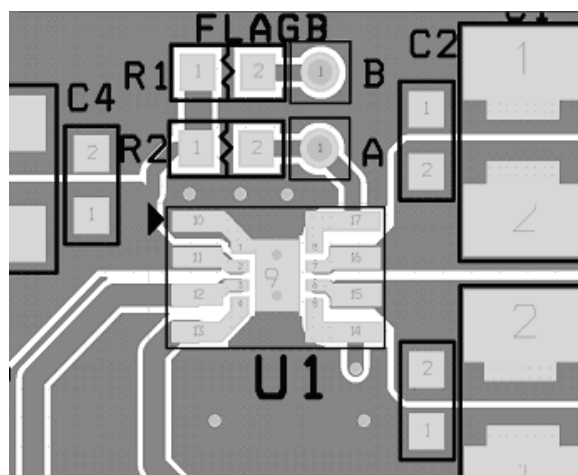
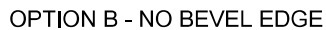
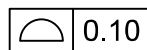
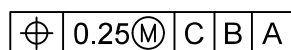


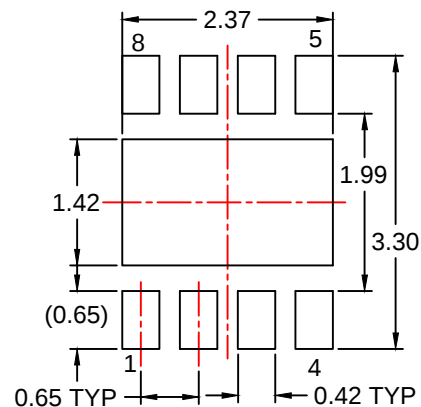
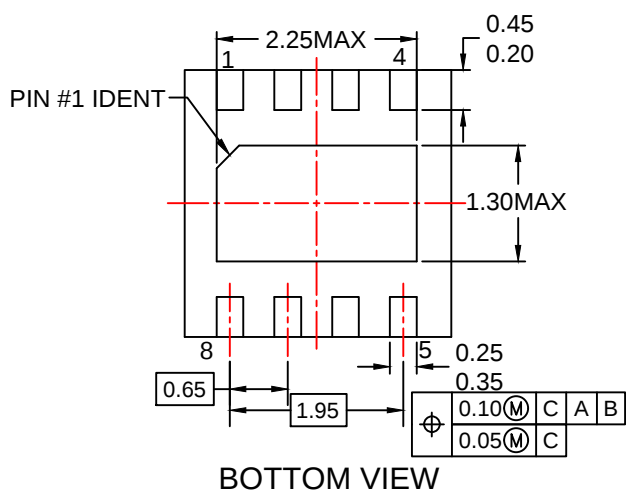
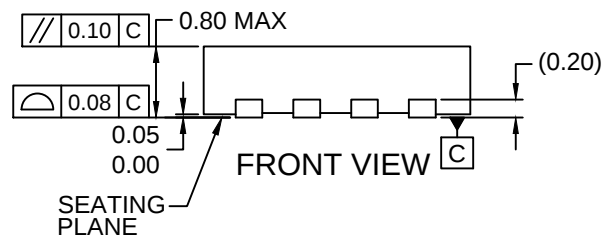
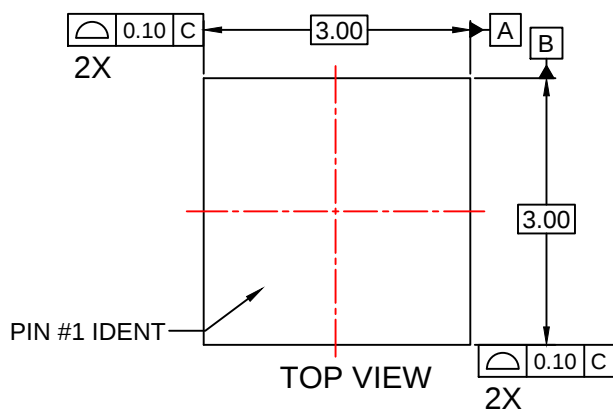
Figure 45. Zoom-In to Top Layer

## Related Resources

[\*FPF2300/02/03 Evaluation Board User Guide: Power Switch for USB Applications\*](#)



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